Diode Semiconductor Device - Page 1 of 1



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**Inclosure Material:** Metal **Overall Length:** 0.179 inches **Mounting Facility Quantity:** 1 **Mounting Method:** Threaded stud **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 nonrepetitive peak reverse voltage, peak total value, gate terminal open-circuited **Current Rating Per Characteristic:** 35.00 amperes drain current horsepower metric **Power Rating Per Characteristic:** 30.0 watts small-signal input power, common-collector preset Maximum Operating Tempurature Per Measurement Point: 125.0 degrees celsius case **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug Shelf Life: N/a Unit Of Measure: ---**Demilitarization:** No Fiig: A110a0